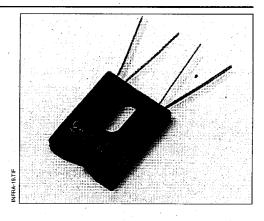
HOA1160

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (-55°C to +100°C)
- Low profile to facilitate stacking



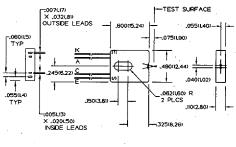
DESCRIPTION

This compact reflective sensor consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1160-001, -002) or photodarlington (HOA1160-003), encased side-by-side on converging optical axes, in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. Flexibility of use is enhanced by a mounting arrangement which allows an adjustment of 0.15 in.(3.80 mm) in the distance from the reflective surface. The HOA1160 series employs hermetically sealed, metal can packaged components. For additional component information see SE2460, SD2440, and SD2410.

Housing material is acetal copolymer. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals $\pm 0.010(0.25)$ 2 plc decimals $\pm 0.020(0.51)$



FRA-34.DIM

Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

HOA1160

Reflective Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IREMITTER	in t					
Forward Voltage	V _F			1,6	- V √ .	l⊫20 mA
Reverse Leakage Current	I _R			10	μA	V _R =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V(BR)CEO				V	lc=100 μA
HOA1160-001, -002		30		galerman. 1		
HOA1160-003		15		Mu		
Collector-Emitter Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current	ICEO				nA.	Vce=10.V
HOA1160-001, -002				100		IF=0
HØA1160-003				250	DOM:	
COUPLED CHARACTERISTICS						
On-State Collector Current	fc(ON)				mA	V _{CE} =5 V
HOA1160-001		0.5				I _F =30 mA
HOA1160-002		2.0				(1)
HOA1160-003		5.0				AND THE PROPERTY OF THE PROPER
Collector-Emitter Saturation Voltage	V _{CE} (SAT)		5.7		V	l _{F≕} 30 mA, (1)
HOA1160-001				0.4		I _C ≕60 μA
HOA1160-002				0.4		lc=250 μA
HQA1160-003		K. K		1.1		Ic=630 μA
Rise And Fall Time	tr, tr	1			μs	V _{CC} =5 V, I _C =1 mA
HOA1160-001, -002			15			R _L =1000 Ω
HOA1160-003			75			R _L =100 Ω

1. Test surface is a front surface mirror located 0.075 in (1.90 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

IR EMITTER Power Dissipation

125 mW⁽¹⁾ 3 V

Reverse Voltage

50 mA

Continuous Forward Current DETECTOR

TRANS.

DARLINGTON 15 V

Collector-Emitter Voltage **Emitter-Collector Voltage** 30 V 5 V

5 V 125 mW⁽¹⁾

Power Dissipation Collector DC Current 125 mW⁽¹⁾ 30 mA

30 mA

Notes

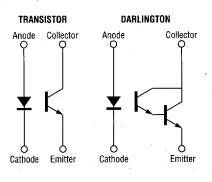
1. Derate linearly at 1.19 mW/°C above 25°C.

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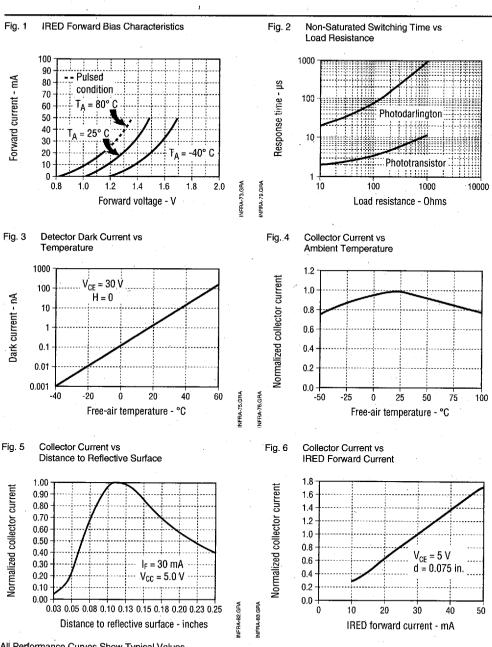
4551830 0019045 T59

SCHEMATIC



HOA1160

Reflective Sensor



All Performance Curves Show Typical Values



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Mouser Electronics

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Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Honeywell:

HOA1160-001 HOA1160-002